SPnT Coaxial Switches DC to 6 GHz, DC to 20 GHz, DC to 26.5 GHz, DC to 40 GHz

Radiall's TITANIUM switches are optimised to perform at a high level over an extended life span. With outstanding RF performances, and a guaranteed Insertion Loss repeatability of 0.03 dB over a life span of 2,5 million switching cycles. RADIALL TITANIUM switches are perfect for automated test and measurement equipment, as well as signal monitoring devices.

PART NUMBER SELECTION

R 514 . 73 . . 7 . NEW

RF Connectors :
3 : SMA up to 6 GHz
4 : SMA up to 20 GHz
F : SMA up to 26.5 GHz
8 : SMA 2.9 up to 40 GHz

Documentation :
- : Certificate Of Conformity
C : Calibration certificate
R : Calibration certificate + RF curves

Type :
7 : Latching + Self cut-off + Auto Reset + Indicators

Actuator Terminal :
7 : HE 10 receptacle, delivered with 750 mm (30 inches) ribbon cable + HE10 connector

Number of Positions :
4 : 4 positions
6 : 6 positions

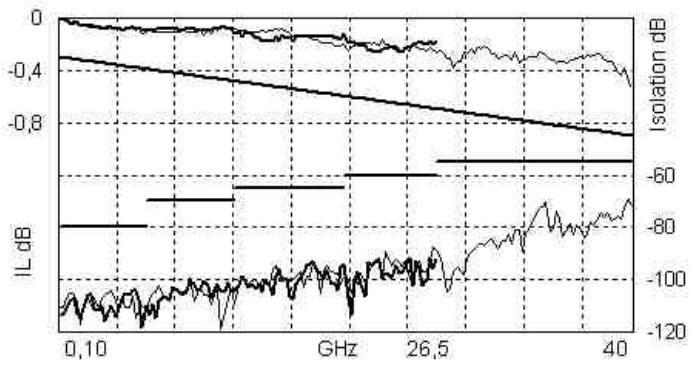
Options :
1 : Positive common (without TTL)
2 : TTL/5V logic with 24 Vdc supply

PICTURE

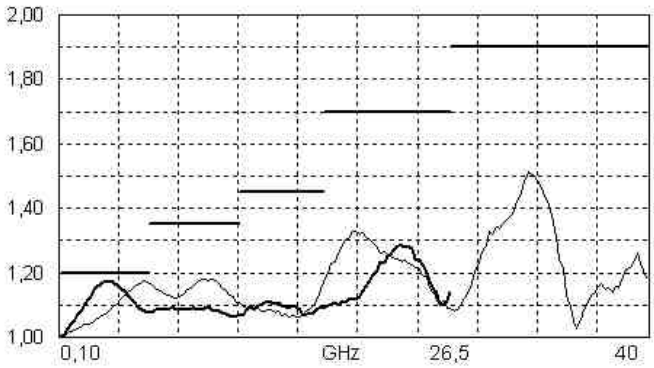
RF PERFORMANCES

PART NUMBER	R5143734-7 R5143736-7	R5144734-7 R5144736-7	R514F734-7 R514F736-7	R5148734-7 R5148736-7
Frequency Range GHz	DC to 6	DC to 20	DC to 26.5	DC to 40
Impedance Ohms	50			
Insertion Loss dB (Maximum)	0.3 + 0.015 x frequency (GHz)			
Isolation dB (Minimum)	80	DC to 6 GHz : 80 6 to 12.4 GHz : 70 12.4 to 20 GHz : 65	DC to 6 GHz : 80 6 to 12.4 GHz : 70 12.4 to 20 GHz : 65 20 to 26.5 GHz : 60	DC to 6 GHz : 80 6 to 12.4 GHz : 70 12.4 to 20 GHz : 65 20 to 26.5 GHz : 60 26.5 to 40 GHz : 55
V.S.W.R. (Maximum)	1.20	DC to 6 GHz : 1.20 6 to 12.4 GHz : 1.35 12.4 to 18 GHz : 1.45 18 to 20 GHz : 1.70	DC to 6 GHz : 1.20 6 to 12.4 GHz : 1.35 12.4 to 18 GHz : 1.45 18 to 26.5 GHz : 1.70	DC to 6 GHz : 1.20 6 to 12.4 GHz : 1.35 12.4 to 18 GHz : 1.45 18 to 26.5 GHz : 1.70 26.5 to 40 GHz : 1.90
Third order Inter Modulation	-120 dBc typical (2 carriers 20W)			
Repeatability (measured at 25°C)	0.03 dB			0.05 dB

TYPICAL RF PERFORMANCES



Insertion Loss and Isolation



V.S.W.R.

ADDITIONAL SPECIFICATIONS

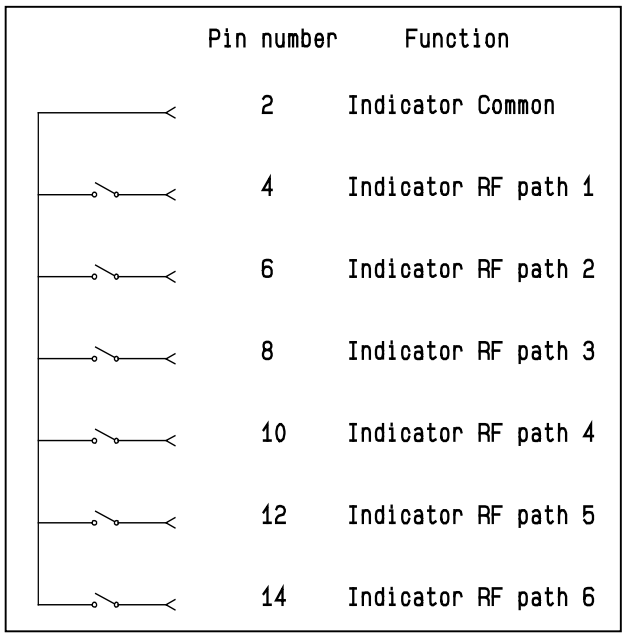
Operating mode		**Latching**	
Nominal operating voltage (across operating temperature) Vdc		**24** (20 / 32)	
Coil resistance (+/-10%) Ohms		120	
Nominal operating current at 23℃ mA		200	
Maximum stand-by current mA		50	
Average power		RF path Cold switching : see Power Rating Chart on page 8 Hot switching : 1 Watt CW	
		Internal terminations 1 Watt average into 50 Ω	
TTL input	High Level	3 to 7 V	1.4 mA max at Vcc = Max
	Low Level	0 to 0.8 V	
Indicator specifications		Maximum withstanding voltage : 60V Maximum current capacity : 150 mA Maximum « ON » resistance : 2.5 Ω Minimum « OFF » resistance : 100 MΩ	
Switching time (max) ms		15	
Life (min**) for**	SMA	2,5 million cycles	
	SMA 2.9	1 million cycles	
Connectors		SMA – SMA 2.9	
Actuator terminal		HE10 ribbon receptacle	
Weight (max) g		230	

ENVIRONMENTAL SPECIFICATIONS

Operating temperature range ℃	-25 to +75
Storage temperature range ℃	-55 to +85
Temperature cycling (MIL-STD-202 , Method 107D , Cond.A) ℃	-55 to +85 (10 cycles)
Vibration (MIL STD 202 , Method 204D , Cond.D)	10-2000 Hz , 10g operating
Shock (MIL STD 202 , Method 213B , Cond.C)	50g / 6 ms , ½ sine operating
Moisture resistance (MIL STD 202 , Method 106E , Cond.E)	65℃, 95% RH, 10 days
Altitude storage (MIL STD 202 , Method 105C , Cond.B)	50,000 feet (15,240 meters)
RFI (MIL STD 1344 , Method 3008 or IEC 61726)	55dB at 20GHz
Magnetic field	< 5.10^{-5} gauss at 1 meter

ELECTRONIC POSITION INDICATORS

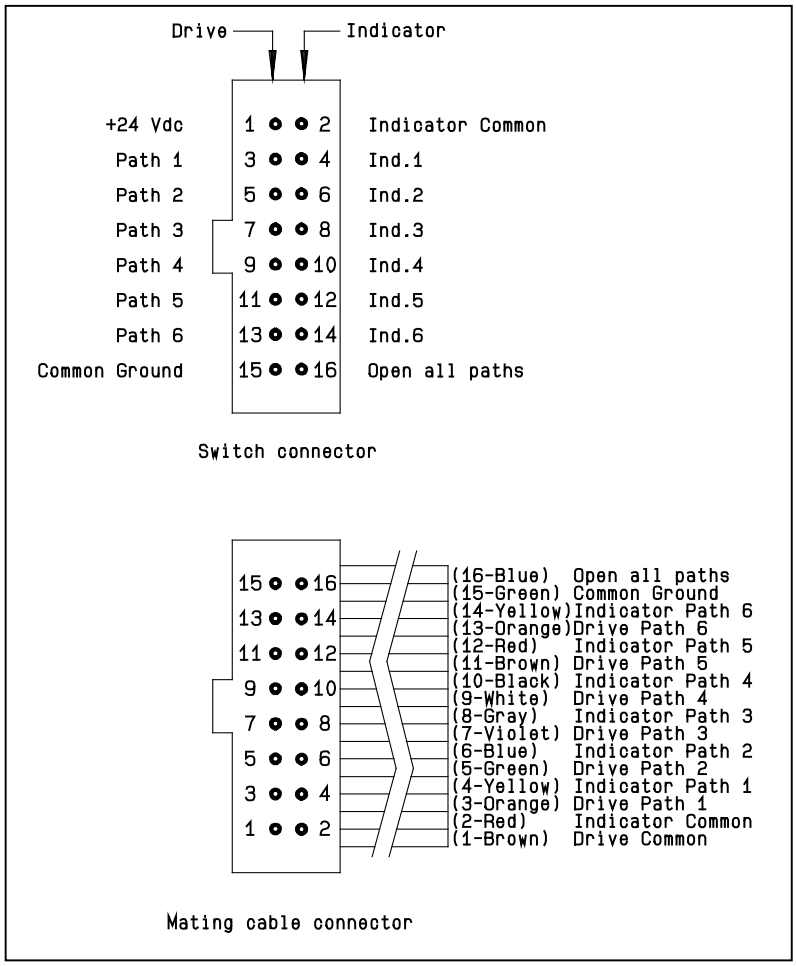
The electronic position indicators utilise photo-MOS transistors which are driven by the mechanical position of the RF paths moving elements. The circuitry consists of a common which can be connected to an output corresponding to selected RF path. If one or several RF paths are closed, the corresponding indicators are connected to the common. The photo-MOS transistors are configured for AC and/or DC operation. The electronic position indicators require the supply (20 to 32 VDC) to be connected to pin 1 and ground connected to pin 15.



Ways 1 and 4 are not connected for SP4T switches.

DRIVING THE SWITCH : Type 7 : with TTL (option "2") / without TTL (option "1").

Each RF path can be closed by applying Ground or TTL "High" for option 2 to the corresponding "drive" pin. In general, except for Make-Before-Break drive, all other RF paths are simultaneously opened by internal logic.



Ways 1 and 4 are not connected for SP4T switches.

Standard drive option "1"

- Connect pin 15 to ground.
- Connect pin 1 to supply (+20 VDC to +32 VDC)
- Select (close) desired RF path by applying Ground to the corresponding "drive" pin (Ex: apply Ground to pin 3 to close RF path 1).
- To select another path, ensure that all unwanted RF path "drive" pins are disconnected from Ground (to prevent multiple RF path engagement). Apply Ground to the "drive" pin which corresponds to the desired RF path.
- To open all RF paths, ensure that all RF path "drive" pins are disconnected from Ground. Complete the operation by applying Ground to pin 16.

TTL drive option "2"

- Connect pin 15 to ground.
- Connect pin 1 to supply (+20 VDC to +32 VDC)
- Select (close) desired RF path by applying TTL "High " to the corresponding "drive" pin (Ex: apply TTL "High" to pin 3 to close RF path 1).
- To select another path, ensure that all unwanted RF path "drive" pins are in TTL "Low" position (to prevent multiple RF path engagement). Apply TTL "High" to the "drive" pin which corresponds to the desired RF path.
- To open all RF paths, ensure that all RF path "drive" pins are in TTL "Low" position. Complete the operation by applying TTL "High" to pin 16.

Break-Before-Make

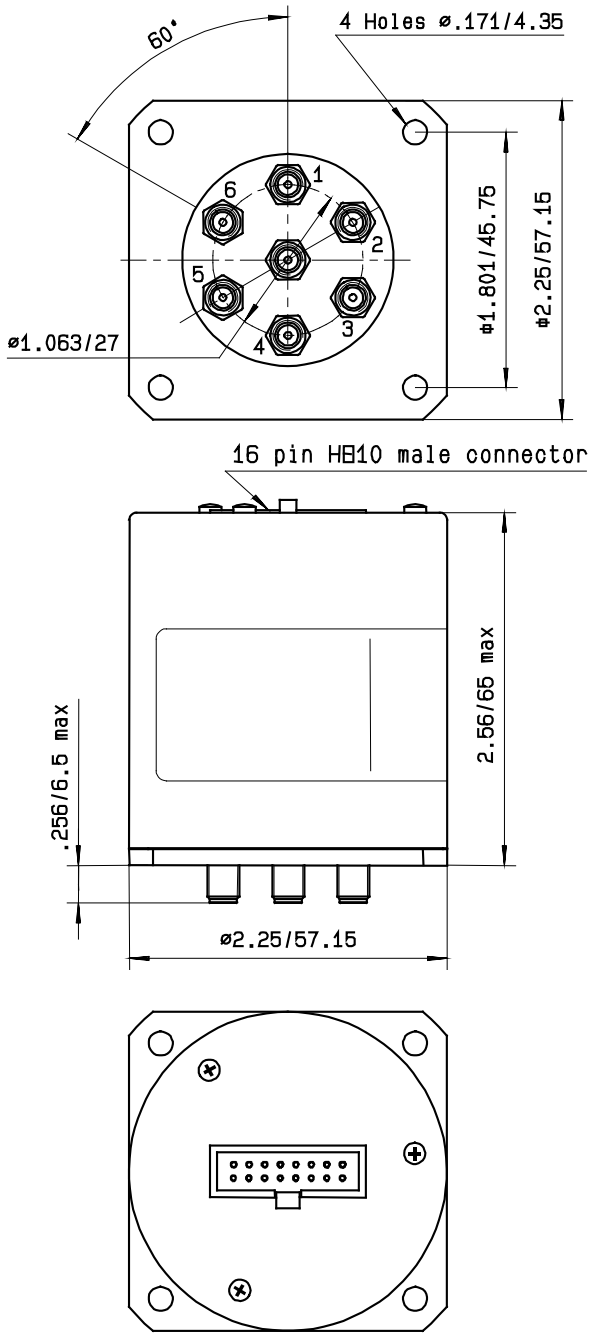
Open the undesired RF path. After 15 ms (minimum), close the new RF port.

Make-Before-Break

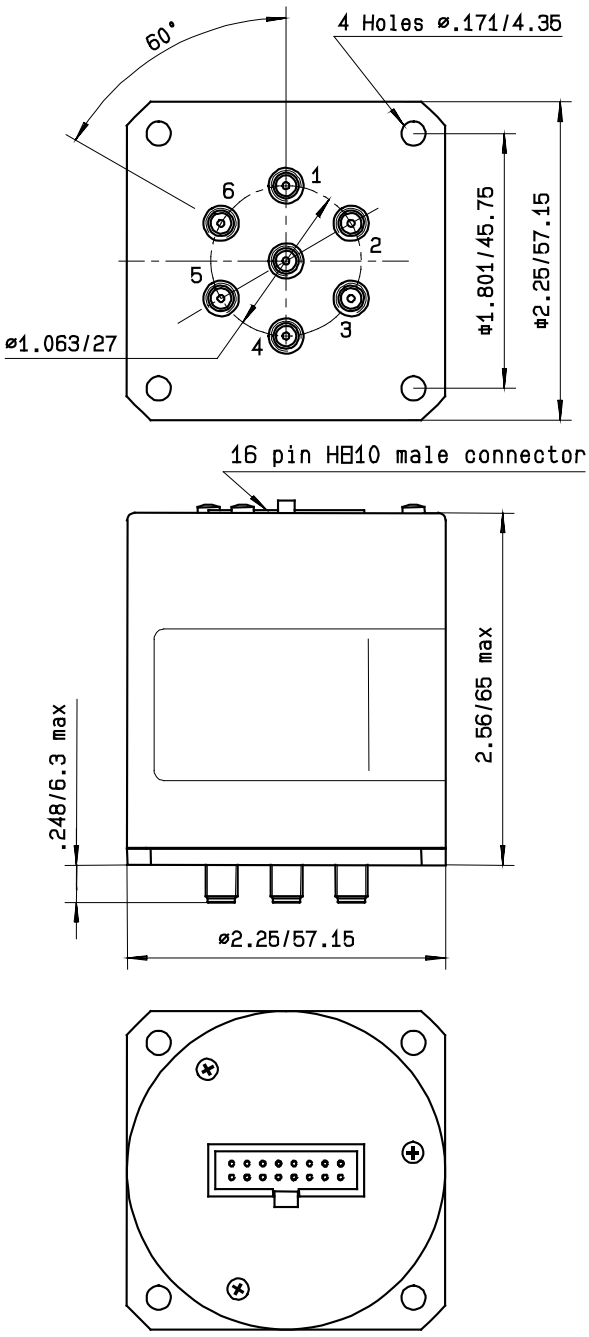
Ensure that the previously selected RF path "drive" is connected to Ground (or TTL "High" for option "2", then close the new RF path.

TYPICAL OUTLINE DRAWING

SMA connectors



SMA 2.9 connectors



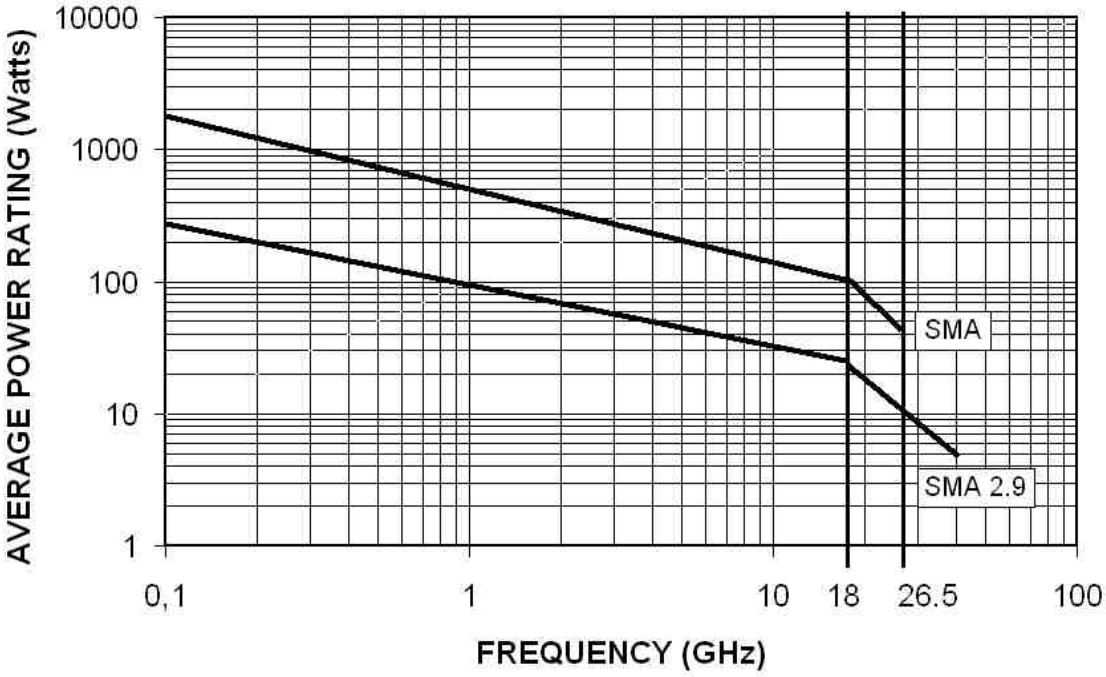
All dimensions are in inches/millimetres.

Ways 1 and 4 are not connected for SP4T

POWER RATING CHART

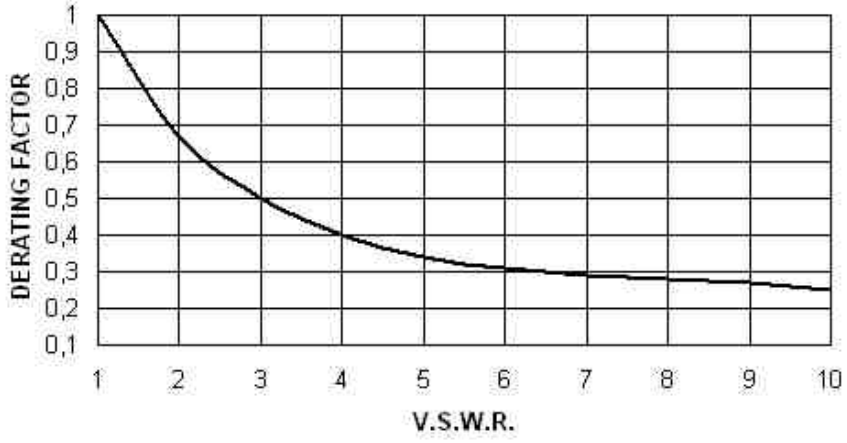
This graph is based on the following conditions :

- Ambient temperature : + 25°C
- Sea level
- V.S.W.R. : 1 and cold switching



DERATING FACTOR VERSUS V.S.W.R.

The average power input must be reduced for load V.S.W.R. above 1.



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Данный компонент на территории Российской Федерации

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Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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